

#### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C	
-40V	25mΩ @ V <sub>GS</sub> = -10V	-6.5A	
	45mΩ @ V <sub>GS</sub> = -4.5V	-4.8A	

## **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

#### Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low RDS(ON) Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/guality/product-definitions/

#### **Mechanical Data**

Package: SO-8

8 D1 7 D1

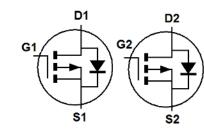
6 D2

5 D2

- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)

S11 G12 S23 G24 Top View

SO-8



Device Symbol

## Ordering Information (Note 4)

Part Number	Bookago	Pa	Packing	
	Package	Qty.	Carrier	
DMP4026LSD-13	SO-8	2500	Reel	

Top View

Pin-Out

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



 $\begin{array}{l} \bigcirc 11 = \mbox{Manufacturer's Marking}\\ \hline \ensuremath{\underline{P4}026LD} = \mbox{Product Type Marking Code}\\ \hline \hline \ensuremath{\underline{YY}} WW = \mbox{Date Code Marking}\\ \hline \hline \ensuremath{\underline{YY}} = \mbox{Year (ex: 23 = 2023)}\\ \hline WW = \mbox{Week (01 to 53)} \end{array}$ 



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) $V_{GS} = -10V$	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	-6.5 -5.2	А
Maximum Body Diode Forward Current (Note 6)			ls	-6.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	-46	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	-46	А
Avalanche Current, L = 0.3mH			las	-20	A
Avalanche Energy, L = 0.3mH			E <sub>AS</sub>	62	mJ

## **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)		PD	1.3	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	96.4	°C/W	
Total Power Dissipation (Note 6)		PD	1.7	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	73.1	°C/W	
Thermal Resistance, Junction to Case	Rejc	10.9	-0/00		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

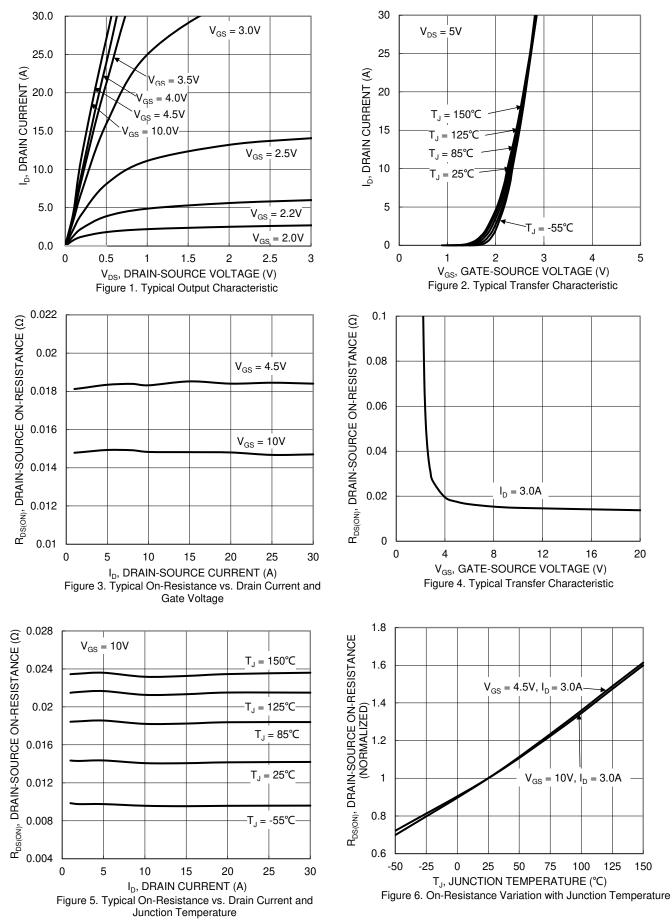
#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	_	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-0.8	—	-1.8	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	D	—	15.1	25	mΩ	$V_{GS} = -10V, I_D = -3A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	18.3	45	mΩ	$V_{GS} = -4.5V, I_{D} = -3A$	
Diode Forward Voltage	Vsd	_	-0.7	-1.0	V	VGS = 0V, IS = -1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	2064	_	pF	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	212	_			
Reverse Transfer Capacitance	Crss	_	183	_			
Gate Resistance	Rg	_	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -10V)	Q <sub>G</sub>	_	45.8	_			
Total Gate Charge (V <sub>GS</sub> = -4.5V)	QG	_	23.5	_	nC	$V_{DS} = -20V. I_{D} = -3A$	
Gate-Source Charge	Qgs	_	5	_		$v_{DS} = -20v, ID = -3A$	
Gate-Drain Charge	Qgd	_	6.7	_			
Turn-On Delay Time	td(ON)	_	4.3	_		$V_{GS} = -10V, V_{DD} = -20V, R_G = 6\Omega,$	
Turn-On Rise Time	tR	_	4.7	_	ns		
Turn-Off Delay Time	tD(OFF)		71.8	_		I <sub>D</sub> = -3A	
Turn-Off Fall Time	tF	_	23.9	_	]		
Body Diode Reverse Recovery Time	trr		17.3	_	ns	Is = -3A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	QRR	_	8.7		nC	Is = -3A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

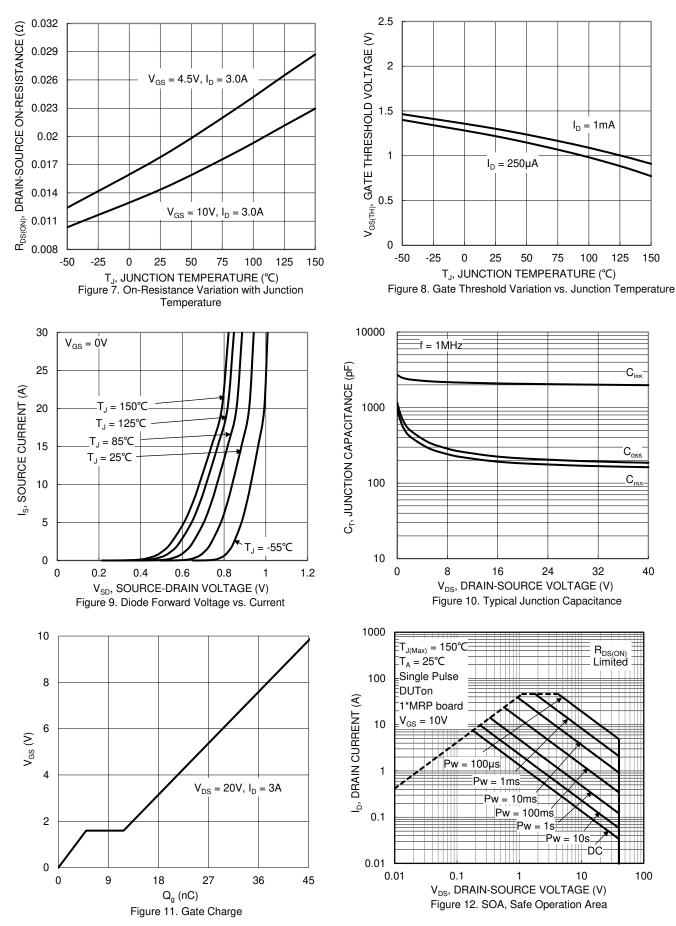


### DMP4026LSD



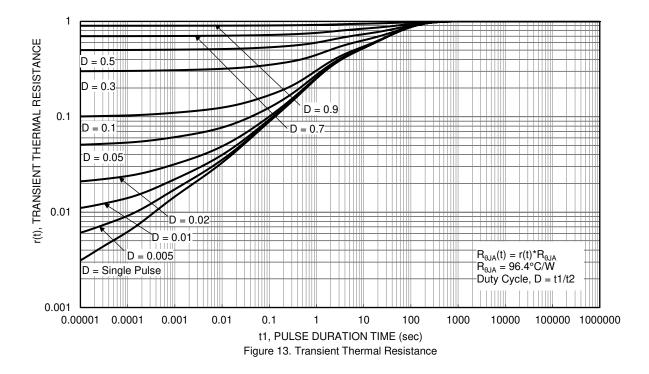
DMP4026LSD Document number: DS44830 Rev. 2 - 2





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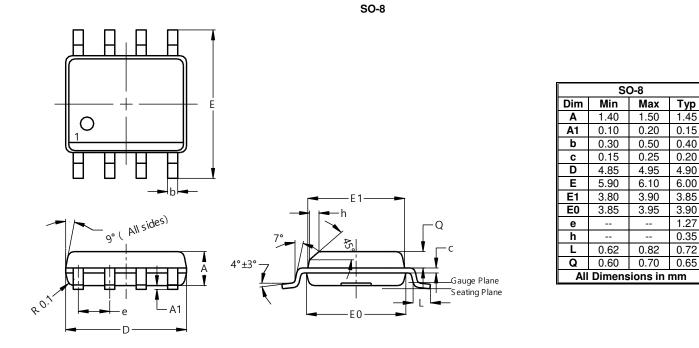






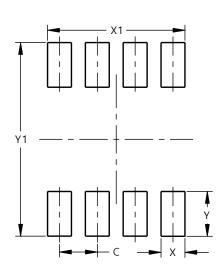
### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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